



100V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	Rds(ON)	I _D T _A = +25°C
-100V	4.2Ω @ V _{GS} = -10V	-0.27A
-1007	5.0Ω @ V _{GS} = -4.0V	-0.24A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- DC-DC converters
- Power-management functions
- Battery-operated systems and solid-state relays
- Drivers: relays, solenoids, lamps, hammers, displays, memories, transistors, etc.

SOT23 (Standard)





Top View

Features and Benefits

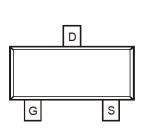
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface-Mount Package
- ESD Protected up to 2KV (HBM)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

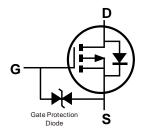
An automotive-compliant part is available under separate datasheet (DMP10H4D2SQ)

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)







Equivalent Circuit

Ordering Information (Note 4)

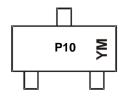
		-	
Part Number	Dockers	Pac	king
Part Number	Package	Qty.	Carrier
DMP10H4D2S-7	SOT23 (Standard)	3,000	Tape & Reel
DMP10H4D2S-13	SOT23 (Standard)	10,000	Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information



P10 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: L = 2024) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2015		2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	С		L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	-100	V	
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 6) Vgs = -10V	ΙD	-0.27 -0.21	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle ≤1%)	I _{DM}	-1.0	Α	
Maximum Body Diode Continuous Current (Note 6)		Is	-0.27	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation		(Note 5)	ם	0.38	W
Total Fower Dissipation		(Note 6)	PD	0.44	۷V
Thermal Resistance, Junction to Ambient Steady		(Note 5)	$R_{\theta JA}$	333	
Thermal Resistance, Junction to Ambient State		(Note 6)	RθJA	282	°C/W
Thermal Resistance, Junction to Case	(Note 6)	Rejc	115		
Operating and Storage Temperature Range			T_{J}, T_{STG}	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.



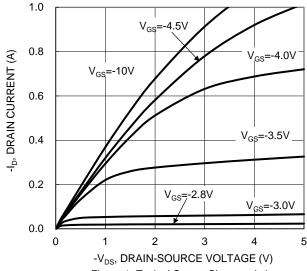
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

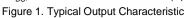
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-100	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	V _{DS} = -100V, V _{GS} = 0V	
Gate-Body Leakage	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	-1.0	-2.3	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Prais Course On Registence	Descou	_	2.8	4.2	Ω	V _{GS} = -10V, I _D = -0.5A	
Static Drain-Source On-Resistance	RDS(ON)	_	3.2	5.0	12	VGS = -4.0V, ID = -0.1A	
Diode Forward Voltage	V_{SD}	_	-0.82	-1.3	V	V _{GS} = 0V, I _S = -0.2A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	87	_		051/1/ 01/	
Output Capacitance	Coss	_	5.6	_	pF	V _{DS} = -25V, V _{GS} = 0V, If = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	2.9	_		T = 1.0MHZ	
Gate Resistance	Rg	_	15.3		Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz	
Total Gate Charge	Qg	_	1.8	_		V 20V V 40V	
Gate-Source Charge	Qgs	_	0.3	_	nC	V _{DS} = -80V, V _{GS} = -10V,	
Gate-Drain Charge	Q_{gd}	_	0.5	_		ID = -0.5A	
Turn-On Delay Time	tD(ON)	_	3.3	_			
Turn-On Rise Time	tR	_	2.6	_		$V_{DS} = -50V, I_{D} = -0.5A,$	
Turn-Off Delay Time	t _{D(OFF)}	_	8.4	_	ns	$V_{GS} = -10V$, $R_G = 10\Omega$	
Turn-Off Fall Time	tF		4.9	_		1	
Reverse Recovery Time	trr	_	17.8	_	ns	V _R = -100V, I _F = -1.0A,	
Reverse Recovery Charge	Qrr	_	24.8	_	nC	di/dt = 100A/µs	

Notes:

^{7.} Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.







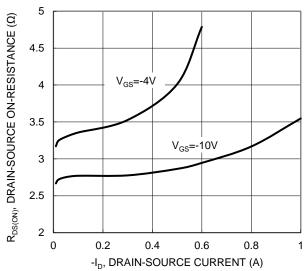


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

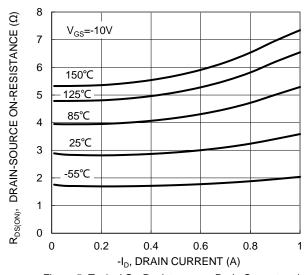


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

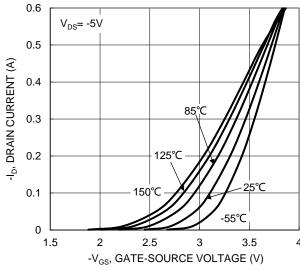


Figure 2. Typical Transfer Characteristic

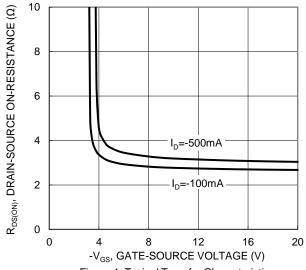


Figure 4. Typical Transfer Characteristic

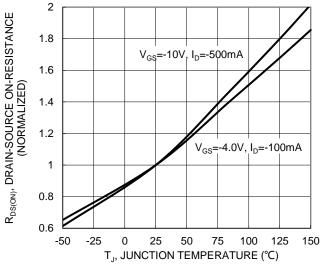
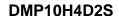


Figure 6. On-Resistance Variation with Junction Temperature





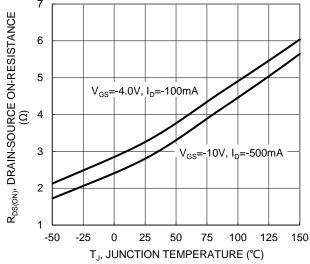


Figure 7. On-Resistance Variation with Junction Temperature

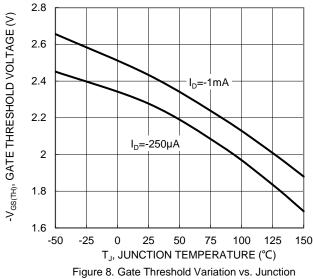


Figure 8. Gate Threshold Variation vs. Junction Temperature

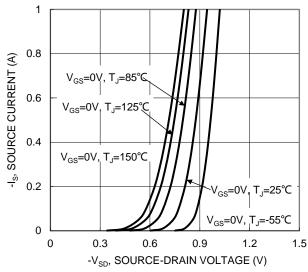
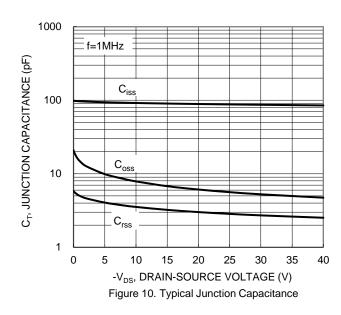
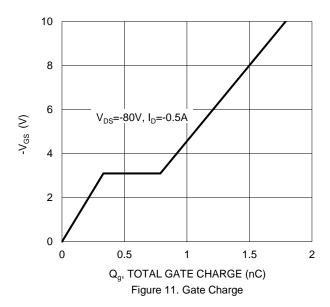


Figure 9. Diode Forward Voltage vs. Current





 $\begin{array}{c} 10 \\ \hline \\ R_{DS(ON)} \text{ Limited} \\ \hline \\ 0.1 \\ \hline \\ P_{W}=10 \\ \hline \\ P_{W}=10 \\ \hline \\ P_{W}=100 \\ \hline \\ P_{W}=100$

Figure 12. SOA, Safe Operation Area



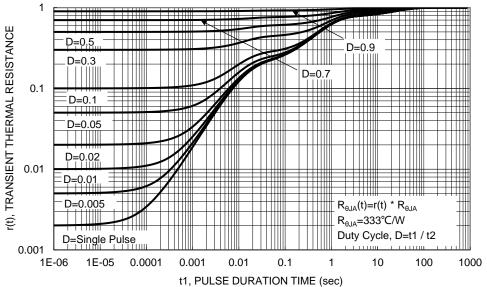


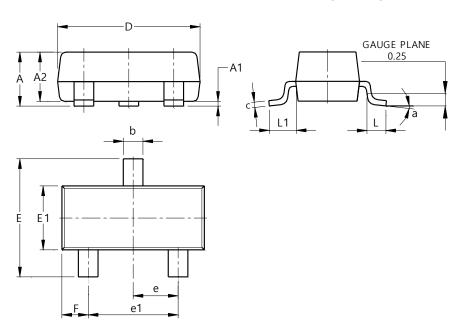
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Standard)

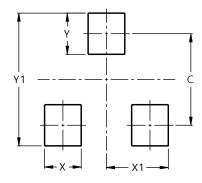


SOT23 (Standard)							
Dim	Min	Max	Тур				
Α	0.90	1.15	1.025				
A1	0.00	0.10	0.05				
A2	0.85	1.10	0.975				
b	0.30	0.51	0.40				
С	0.080	0.202	0.11				
D	2.80	3.00	2.90				
Е	2.25	2.55	2.40				
E1	1.20	1.40	1.30				
е	0.89	1.03	0.915				
e1	1.78	2.05	1.83				
F	0.40	0.60	0.535				
L1	0.45	0.61	0.55				
L	0.25	0.55	0.40				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Standard)



Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Y	0.9
V1	2.0



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